

CD54HC4351, CD74HC4351, CD74HC4352

Data sheet acquired from Harris Semiconductor SCHS213C

is defined inductor

September 1998 - Revised July 2003

High-Speed CMOS Logic Analog Multiplexers/Demultiplexers with Latch

Features

• Wide Analog Input Voltage Range ±5V (Max)

· Low "On" Resistance

- V_{CC} - V_{EE} = 4.5 V_{CC} - V_{FE} = 9 V_{CC} - V_{FE} - 9 V_{CC} - V_{FE} = 9 V_{CC} - V_{FE} - 9 V_{CC} - V_{CC} - V_{FE} - 9 V_{CC} - V_{CC} - V

- Low Crosstalk Between Switches
- Fast Switching and Propagation Speeds
- · "Break-Before-Make" Switching
- Wide Operating Temperature Range . . . -55°C to 125°C
- HC Types
 - 2V to 6V Operation, Control; 0V to 10V Switch
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation, Control; 0V to 10V Switch
 - Direct LSTTL Input Logic Compatibility,
 V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, I_I \leq 1 μ A at V_{OL}, V_{OH}

Description

The 'HC4351, CD74HCT4351, and CD74HC4352 are digitally controlled analog switches which utilize silicon-gate

CD54HC4351

(CERDIP)

CMOS technology to achieve operating speeds similar to LSTTL with the low power consumption of standard CMOS integrated circuits.

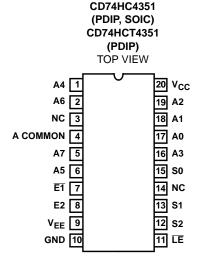
These analog multiplexers/demultiplexers are, in essence, the HC/HCT4015 and HC4052 preceded by address latches that are controlled by an active low Latch Enable input ($\overline{\text{LE}}$). Two Enable inputs, one active low ($\overline{\text{E1}}$), and the other active high (E2) are provided allowing enabling with either input voltage level.

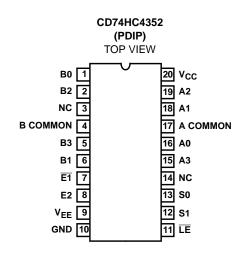
Ordering Information

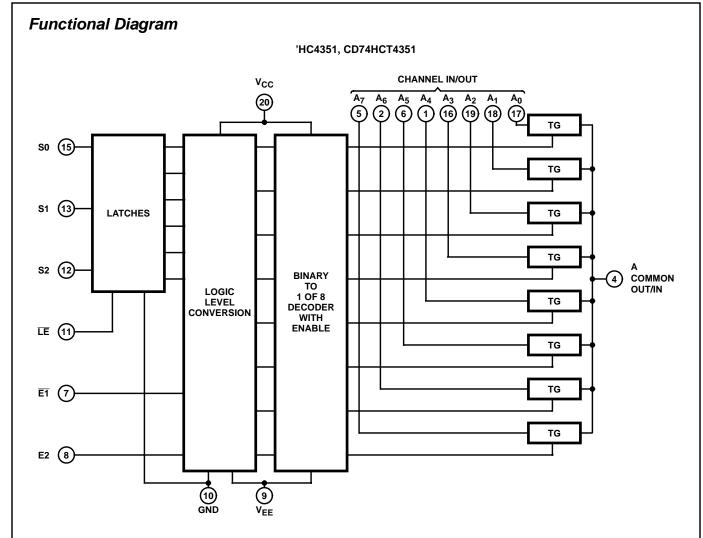
PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC4351F3A	-55 to 125	20 Ld CERDIP
CD74HC4351E	-55 to 125	20 Ld PDIP
CD74HC4351M	-55 to 125	20 Ld SOIC
CD74HC4351M96	-55 to 125	20 Ld SOIC
CD74HCT4351E	-55 to 125	20 Ld PDIP
CD74HC4352E	-55 to 125	20 Ld PDIP

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel.

Pinouts







TRUTH TABLE 'HC4351, CD74HCT4351

	INI	PUT STAT	ES		(NOTE 1) "ON"
<u>E1</u>	E2	S2	S 1	S0	SWITCHES LE = H
L	Н	L	L	L	A ₀
L	Н	L	L	Н	A ₁
L	Н	L	Н	L	A ₂
L	Н	L	Н	Н	A ₃
L	Н	Н	L	L	A ₄
L	Н	Н	L	Н	A ₅
L	Н	Н	Н	L	A ₆
L	Н	Н	Н	Н	A ₇
Н	L	Х	Х	Х	None

H = High Voltage Level, L = Low Voltage Level, X = Don't Care NOTE:

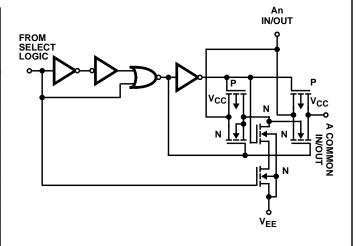
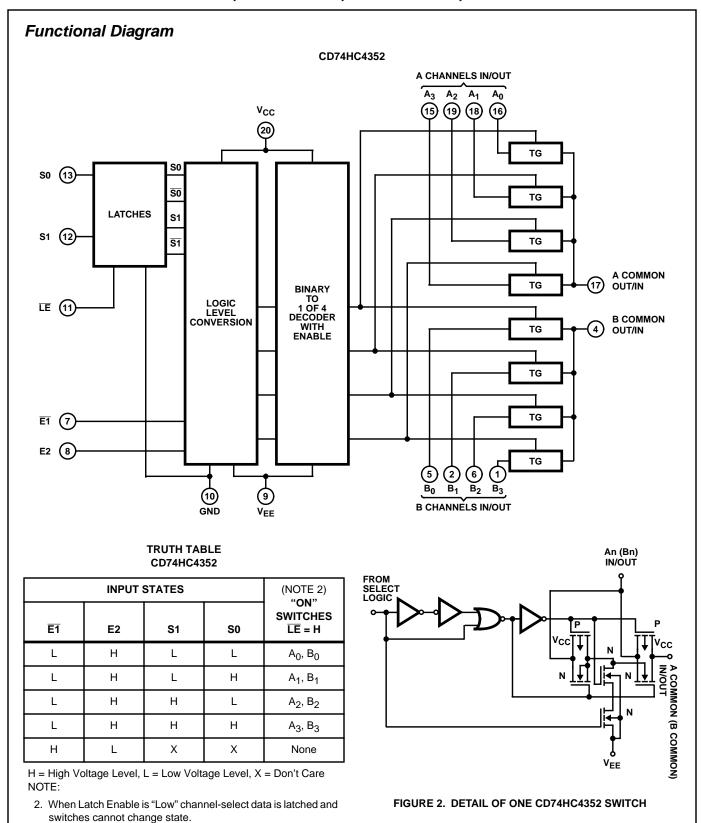


FIGURE 1. DETAIL OF ONE HC/HCT4351 SWITCH

^{1.} When $\overline{\text{LE}}$ is low S0-S2 data are latched and switches cannot change state.



Absolute Maximum Ratings

DC Supply Voltage, V _{CC} 0.5V to 7V DC Supply Voltage, V _{CC} - V _{EE} 0.5V to 10.5V DC Supply Voltage, V _{EE} 0.5V to -7V DC Input Diode Current, $I_{\rm IK}$
For $V_1 < -0.5V$ or $V_1 > V_{CC} = 0.5V + 0.5V +$
DC Switch Diode Current, I _{OK}
For $V_I < V_{EE}$ -0.5V or $V_I < V_{CC} + 0.5V$ ±25mA
DC Switch Current, I _{OK} (Note 3)
For $V_I > V_{EE}$ -0.5V or $V_I < V_{CC} + 0.5V$ ±20mA
DC Output Diode Current, I _{OK}
For $V_0 < -0.5V$ or $V_0 > V_{CC} + 0.5V$
DC Output Source or Sink Current per Output Pin, IO
For $V_O > -0.5V$ or $V_O < V_{CC} + 0.5V$ ±25mA
DC V _{CC} or Ground Current, I _{CC}

Thermal Information

Thermal Resistance (Typical, Note 4)	θ_{JA} (°C/W)
E (PDIP) Package	69
M (SOIC) Package	
Maximum Junction Temperature	150 ^o C
Maximum Storage Temperature Range	65°C to 150°C
Maximum Lead Temperature (Soldering 10s)	300°C
(SOIC - Lead Tips Only)	

Operating Conditions

Temperature Range, T _A
Supply Voltage Range, V _{CC}
HC Types
HCT Types
Supply Voltage Range, V _{CC} - V _{FF}
HC, HCT Types (Figure 3)2V to 10V
Supply Voltage Range, V _{EE}
HC, HCT Types (Figure 4)
DC Input or Output Voltage, V ₁ GND to V _{CC}
Analog Switch I/O Voltage, V _{IS} V _{EE} (Min)
V _{CC} (Max)
Input Rise and Fall Time, t _r , t _f
2V
4.5V 500ns (Max)
6V

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES:

- 3. In certain applications, the external load-resistor current may include both V_{CC} and signal-line components. To avoid drawing V_{CC} current when switch current flows into the transmission gate inputs, the voltage drop across the bidirectional switch must not exceed 0.6V (calculated from R_{ON} values shown in the DC Electrical Specifications table). No V_{CC} current will flow through R_L if the switch current flows into terminal 3 on the 'HC4351 and CD74HCT4351; terminals 3 and 13 on the CD74HC4352.
- 4. The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Area as a Function of Supply Voltage

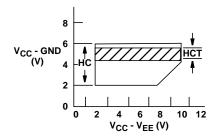


FIGURE 3.

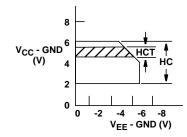


FIGURE 4.

DC Electrical Specifications

			TEST COND	OITIONS			25°C			C TO C	-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	V _{IS} (V)	V _{EE} (V)	V _{CC} (V)	MIN	ТҮР	мах	MIN	мах	MIN	MAX	UNITS
HC TYPES													
High Level Input	V _{IH}	-	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage					4.5	3.15	-	-	3.15	-	3.15	-	V
					6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage					4.5	-	-	1.35	-	1.35	-	1.35	V
					6	-	-	1.8	-	1.8	-	1.8	V
"ON" Resistance	R _{ON}	V _{IH} or	V _{CC} or V _{EE}	0	4.5	-	70	160	-	200	-	240	Ω
I _O = 1mA Figure 9		V _{IL}	,	0	6	-	60	140	-	175	-	210	Ω
· ·			,	-4.5	4.5	-	40	120	-	150	-	180	Ω
			V _{CC} to V _{EE}	0	4.5	-	90	180	-	225	-	270	Ω
				0	6	-	80	160	-	200	-	240	Ω
				-4.5	4.5	-	45	130	-	162	-	195	Ω
Maximum "ON"	ΔR _{ON}	-	-	0	4.5	-	10	-	-	-	-	-	Ω
Resistance Between Any Two Channels			,	0	6	-	8.5	-	-	-	-	-	Ω
,				-4.5	4.5	-	5	-	-	-	-	-	Ω
Switch On/Off	I _{IZ}	V _{IH} or	For Switch	0	6	-	-	±0.1	-	±1	-	±1	μА
Leakage Current 4 Channels (4352)		V _{IL}	OFF: When	-5	5	-	-	±0.2	-	±2	-	±2	μА
Switch On/Off	İ		$V_{IS} = V_{CC}$ $V_{OS} = V_{EE}$;	0	6	-	-	±0.2	-	±2	-	±2	μА
Leakage Current 8 Channels (4351)			When VIS = VEE, VOS = VCC For Switch ON: All Applicable Combinations of VIS and VOS Voltage Levels	-5	5	-	-	±0.4	1	±4	-	±4	μА
Control Input Leakage Current	I _{IL}	V _{CC} or GND	-	0	6	-	-	±0.1	-	±1	-	±1	μА
Quiescent Device Current	I _{CC}	V _{CC} or GND	When	0	6	-	-	8	-	80	-	160	μА
I _O = 0		JUND	$\begin{aligned} & V_{IS} = V_{EE}, \\ & V_{OS} = V_{CC}, \\ & When \\ & V_{IS} = V_{CC}, \\ & V_{OS} = V_{EE} \end{aligned}$	-5	5	-	-	16	-	160	-	320	μА

DC Electrical Specifications (Continued)

			TEST COND	ITIONS			25°C		-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	V _{IS} (V)	V _{EE} (V)	V _{CC} (V)	MIN	ТҮР	мах	MIN	мах	MIN	мах	UNITS
HCT TYPES													
High Level Input Voltage	V _{IH}	-	-	-	4.5 to 5.5	2	-	-	2	-	2	-	٧
Low Level Input Voltage	V _{IL}	-	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	٧
"ON" Resistance	R _{ON}	V _{IH} or	V _{CC} or V _{EE}	0	4.5	-	70	160	-	200	-	240	Ω
I _O = 1mA Figure 9		V _{IL}		-4.5	4.5	-	40	120	-	150	-	180	Ω
			V_{CC} to V_{EE}	0	4.5	-	90	180	-	225	-	270	Ω
				-4.5	4.5	-	45	130	-	162	-	195	Ω
Maximum "ON"	ΔR _{ON}	-	-	0	4.5	-	10	-	-	-	-	-	Ω
Resistance Between Any Two Channels				-4.5	4.5	-	5	-	-	-	-	-	Ω
Switch On/Off	I _{IZ}	V _{IH} or	For Switch	0	6	-	-	±0.1	-	±1	-	±1	μА
Leakage Current 4 Channels (4352)		V _{IL}	OFF: When	-5	5	-	-	±0.2	-	±2	-	±2	μΑ
Switch On/Off			$V_{IS} = V_{CC}$ $V_{OS} = V_{EE}$;	0	6	-	-	±0.2	-	±2	-	±2	μА
Leakage Current 8 Channels (4351)			When VIS = VEE, VOS = VCC For Switch ON: All Applicable Combinations of VIS and VOS Voltage Levels	-5	5	-	-	±0.4	-	±4	-	±4	μА
Control Input Leakage Current	l _l	V _{CC} or GND	-	0	5.5	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device	Icc	Any	When	0	5.5	-	-	8	-	80	-	160	μА
Current I _O = 0		Voltage Be- tween VCC and GND	$V_{IS} = V_{EE},$ $V_{OS} = V_{CC},$ $When$ $V_{IS} = V_{CC},$ $V_{OS} = V_{EE}$	-4.5	5.5	-	-	16	-	160	-	320	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 5)	V _{CC} -2.1	-	-	4.5 to 5.5	-	100	360	-	450	-	490	μА

NOTE:

HCT Input Loading Table

TYPE	INPUT	UNIT LOADS
All	E1, E2, Sn	0.5
(4351, 4352)	LE	1.5

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Table, e.g., 360 μ A max at 25 o C.

^{5.} For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

Switching Specifications Input t_r , $t_f = 6ns$

		TEST	V _{EE}	v _{cc}		25°C			C TO C		C TO 5°C	
PARAMETER	SYMBOL	CONDITIONS	(V)	(V)	MIN	TYP	MAX	MIN	МАХ	MIN	MAX	UNITS
HC TYPES					•							
Propagation Delay, Switch In to Switch Out	t _{PLH} , t _{PHL}	C _L = 50pF	0	2	-	-	35	-	45	-	55	ns
Switch in to Switch Out			0	4.5	-	-	7	-	9	-	11	ns
			0	6	-	-	6	-	8	-	9	ns
			-4.5	4.5	-	-	5	-	7	-	8	ns
Maximum Switch Turn "ON" Delay 4351	t _{PZH} , t _{PZL}	C _L = 50pF	0	2	-	-	300	-	375	-	450	ns
E1, E2, LE to V _{OS}			0	4.5	-	-	60	-	75	-	90	ns
			0	6	-	-	51	-	64	-	77	ns
			-4.5	4.5	-	-	55	-	69	-	83	ns
		C _L = 15pF	-	5	-	27	-	-	-	-	-	ns
aximum Switch Turn "ON" t _{PZH} , t _{PZL} elay 4352	C _L = 50pF	0	2	-	-	350	-	440	-	525	ns	
E1, E2, LE to V _{OS}			0	4.5	-	-	70	-	88	-	105	ns
			0	6	-	-	60	-	75	-	90	ns
			-4.5	4.5	-	-	60	-	75	-	90	ns
		C _L = 15pF	-	5	-	35	-	-	-	-	-	ns
Maximum Switch Turn "ON" Delay 4351	t _{PZH} , t _{PZL}	C _L = 50pF	0	2	-	-	300	-	375	-	450	ns
Sn to V _{OS}			0	4.5	-	-	60	-	75	-	90	ns
			0	6	-	-	51	-	64	-	77	ns
			-4.5	4.5	-	-	50	-	63	-	75	ns
		C _L = 15pF	-	5	-	27	-	-	-	-	-	ns
Maximum Switch Turn "ON" Delay 4352	t _{PZH} , t _{PZL}	C _L = 50pF	0	2	-	-	375	-	470	-	565	ns
Sn to V _{OS}			0	4.5	-	-	75	-	94	-	113	ns
			0	6	-	-	64	-	80	-	96	ns
			-4.5	4.5	-	-	55	-	69	-	83	ns
		C _L = 15pF	-	5	-	35	-	-	-	-	-	ns
Maximum Switch Turn "OFF" Delay 4351	t _{PHZ} , t _{PLZ}	C _L = 50pF	0	2	-	-	250	-	315	-	375	ns
E1 to V _{OS}			0	4.5	-	-	50	-	63	-	75	ns
			0	6	-	-	43	-	54	-	64	ns
			-4.5	4.5	-	-	40	-	50	-	60	ns
		C _L = 15pF	-	5	-	21	-	-	-	-	-	ns

Switching Specifications Input $t_{\text{f}},\,t_{\text{f}}$ = 6ns (Continued)

		TEST	V _{EE}	V _{CC}		25°C			C TO C		C TO 5°C	
PARAMETER	SYMBOL	CONDITIONS	(V)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Maximum Switch Turn "OFF"	t _{PHZ} , t _{PLZ}	C _L = 50pF	0	2	-	-	250	-	315	-	375	ns
Delay 4351 E2 to V _{OS}			0	4.5	-	-	50	-	63	-	75	ns
			0	6	-	-	43	-	54	-	64	ns
			-4.5	4.5	-	-	40	-	50	-	60	ns
		C _L = 15pF	-	5	-	21	-	-	-	-	-	ns
Maximum Switch Turn "OFF"	t _{PHZ} , t _{PLZ}	C _L = 50pF	0	2	-	-	275	-	345	-	415	ns
Delay 4351 LE to V _{OS}			0	4.5	-	-	55	-	69	-	83	ns
			0	6	-	-	47	-	59	-	71	ns
			-4.5	4.5	-	-	45	-	56	-	68	ns
Maximum Switch Turn "OFF"	t _{PHZ} , t _{PLZ}	C _L = 50pF	0	2	-	-	275	-	345	-	415	ns
Delay 4351 Sn to V _{OS}			0	4.5	-	-	55	-	69	-	83	ns
			0	6	-	-	47	-	59	-	71	ns
			-4.5	4.5	-	-	48	-	60	-	71	ns
		C _L = 15pF	-	5	-	21	-	-	-	-	-	ns
Maximum Switch Turn "OFF"	t _{PHZ} , t _{PLZ}	C _L = 50pF	0	2	-	-	275	-	345	-	415	ns
Delay 4352 E1, E2, LE to V _{OS}			0	4.5	-	-	55	-	69	-	83	ns
			0	6	-	-	47	-	59	-	71	ns
			-4.5	4.5	-	-	50	-	63	-	75	ns
		C _L = 15pF	-	5	-	21	-	-	-	-	-	ns
Setup Time 4351	tsu	C _L = 50pF	0	2	-	-	60	-	75	-	90	ns
Sn to LE			0	4.5	-	-	12	-	15	-	18	ns
			0	6	-	-	10	-	13	-	15	ns
			-4.5	4.5	-	-	18	-	23	-	27	ns
Hold Time 4351 and 4352	tH	C _L = 50pF	0	2	5	-	-	5	-	5	-	ns
Sn to LE			0	4.5	5	-	-	5	-	5	-	ns
			0	6	5	-	-	5	-	5	-	ns
			-4.5	4.5	5	-	-	5	-	5	-	ns
Pulse Width 4351 and 4352	t _W	C _L = 50pF	0	2	100	-	-	125	-	150	-	ns
<u>LE</u>			0	4.5	20	-	-	25	-	30	-	ns
			0	6	17	-	-	21	-	26	-	ns
			-4.5	4.5	25	-	-	31	-	38	-	ns
Input (Control) Capacitance	C _I	-	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 6, 7) 4351	C _{PD}	-	-	5	-	50	-	-	-	-	-	pF

Switching Specifications Input t_r , $t_f = 6ns$ (Continued)

		TEST	V _{EE}	Vcc		25°C			C TO °C	-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Power Dissipation Capacitance (Notes 6, 7) 4352	C _{PD}	-	-	5	-	74	-	-	-	-	-	pF
HCT TYPES		•										
Propagation Delay,	t _{PLH} , t _{PHL}	C _L = 50pF	0	4.5	-	-	7	-	9	-	11	ns
Switch In to Switch Out			-4.5	4.5	-	-	5	-	7	-	8	ns
Maximum Switch Turn "ON"	t _{PZH} , t _{PZL}	C _L = 50pF	0	4.5	-	-	75	-	94	-	113	ns
Delay 4351 E1, E2, LE to VOS			-4.5	4.5	-	-	60	-	75	-	90	ns
		C _L = 15pF	-	5	-	35	-	-	-	-	-	ns
Maximum Switch Turn "ON"	t _{PZH} , t _{PZL}	C _L = 50pF	0	4.5	-	-	75	-	94	-	113	ns
Delay 4351 Sn to V _{OS}			-4.5	4.5	-	-	60	-	75	-	90	ns
		C _L = 15pF	-	5	-	35	-	-	-	-	-	ns
Maximum Switch Turn "OFF"	4351	C _L = 50pF	0	4.5	-	-	55	-	69	-	83	ns
Delay 4351 E1 to V _{OS}			-4.5	4.5	-	-	40	-	50	-	60	ns
		C _L = 15pF	-	5	-	23	-	-	-	-	-	ns
Maximum Switch Turn "OFF"	t _{PHZ} , t _{PLZ}	C _L = 50pF	0	4.5	-	-	60	-	75	-	90	ns
Delay 4351 E2 to V _{OS}			-4.5	4.5	-	-	50	-	63	-	75	ns
		C _L = 15pF	-	5	-	23	-	-	-	-	-	ns
Maximum Switch Turn "OFF" Delay 4351	t _{PHZ} , t _{PLZ}	C _L = 50pF	0	4.5	-	-	60	-	75	-	90	ns
LE to V _{OS}			-4.5	4.5	-	-	55	-	69	-	83	ns
Maximum Switch Turn "OFF"	t _{PHZ} , t _{PLZ}	C _L = 50pF	0	4.5	-	-	65	-	81	-	98	ns
Delay 4351 Sn to V _{OS}			-4.5	4.5	-	-	55	-	69	-	83	ns
		C _L = 15pF	-	5	-	23	-	-	-	-	-	ns
Setup Time 4351		C _L = 50pF	0	4.5	-	-	12	-	15	-	18	ns
Sn to LE			-4.5	4.5	-	-	14	-	18	-	21	ns
Hold Time 4351 and 4352		C _L = 50pF	0	4.5	5	-	-	5	-	5	-	ns
Sn to LE			-4.5	4.5	5	-	-	5	-	5	-	ns
Pulse Width 4351	t _W	C _L = 50pF	0	4.5	25	-	-	31	-	28	-	ns
LE			-4.5	4.5	25	-	-	31	-	38	-	ns
Input (Control) Capacitance	Cl	-	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 6, 7) 4351	C _{PD}	-	-	5	-	52	-	-	-	-	-	pF

^{6.} $C_{\mbox{\scriptsize PD}}$ is used to determine the dynamic power consumption, per package.

^{7.} $P_D = C_{PD} \ V_{CC}^2 \ f_i + \Sigma \ (C_L + C_S) \ V_{CC}^2 \ f_o$ where f_i = input frequency, f_o = output frequency, C_L = output load capacitance, C_S = switch capacitance, V_{CC} = supply voltage.

Analog Channel Specifications $T_A = 25^{\circ}C$

PARAMETER	SYMBOL	TEST CONDITIONS	TYPE	V _{EE} (V)	V _{CC} (V)	нс/нст	UNITS
Switch Input Capacitance	Cl		All	-	-	5	pF
Common Capacitance	ССОМ		4351	-	-	25	pF
			4352	-	-	12	pF
Minimum Switch Frequency	f _{MAX}	See Figure 11	4351	-	-	145	MHz
Response at -3dB (Figure 6, 8)		(Notes 8, 9)	4352	-2.25	2.25	165	MHz
			4351	-	-	180	MHz
			4352	-4.5	4.5	185	MHz
Crosstalk Between Any Two Switches		See Figure 10	4351	-	-	N/A	dB
(Note 11)		(Notes 9, 10)	4352	-2.25	2.25	(TBE)	dB
			4351	-	-	N/A	dB
			4352	-4.5	4.5	(TBE)	dB
Sine-Wave Distortion		See Figure 12	All	-2.25	2.25	0.035	%
			All	-4.5	4.5	0.018	%
E or S to Switch Feedthrough Noise		See Figure 13	4351	-	-	-	mV
		(Notes 9, 10)	4352	-2.25	2.25	(TBE)	mV
			4351	-	-	-	mV
			4352	-4.5	4.5	(TBE)	mV
Switch "OFF" Signal Feedthrough		See Figure 14	4351	-	-	-73	dB
(Figure 6, 8)		(Notes 9, 10)	4352	-2.25	2.25	-65	dB
			4351	-	-	-75	dB
			4352	-4.5	4.5	-67	dB

- 8. Adjust input voltage to obtain 0dBm at V_{OS} for, f_{in} = 1MHz.
- 9. V_{IS} is centered at (V_{CC} V_{EE})/2.
- 10. Adjust input for 0dBm.
- 11. Not applicable for 'HC4351 and CD74HCT4351.

Typical Performance Curves

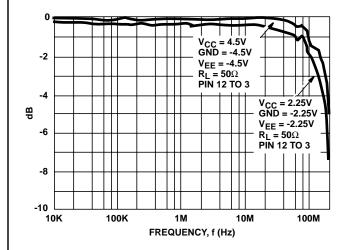


FIGURE 5. CHANNEL ON BANDWIDTH ('HC4351, CD74HCT4351)

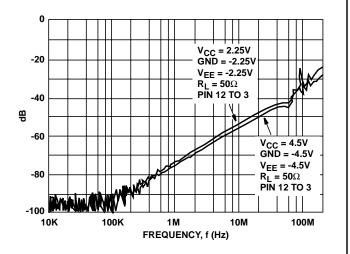


FIGURE 6. CHANNEL OFF FEEDTHROUGH ('HC4351, CD74HCT4351)

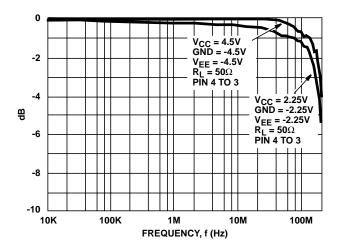


FIGURE 7. CHANNEL ON BANDWIDTH (CD74HC4352)

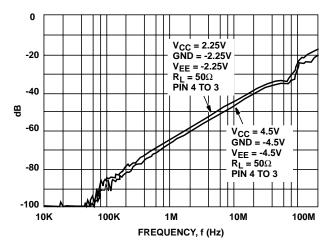


FIGURE 8. CHANNEL OFF FEEDTHROUGH (CD74HC4352)

Typical Performance Curves (Continued)

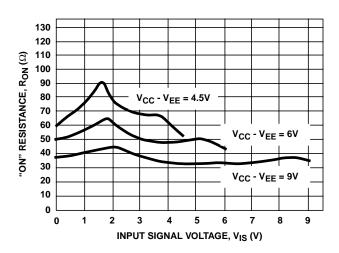


FIGURE 9. TYPICAL ON RESISTANCE vs INPUT SIGNAL VOLTAGE

Analog Test Circuits

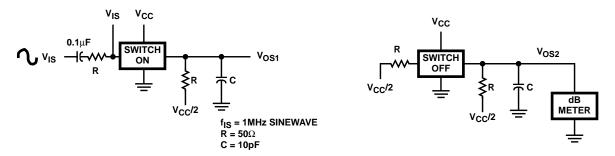
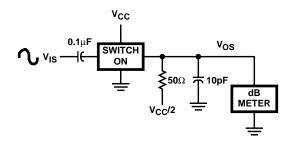


FIGURE 10. CROSSTALK BETWEEN TWO SWITCHES TEST CIRCUIT





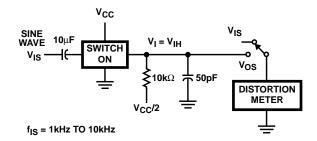
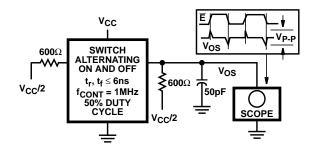


FIGURE 12. TOTAL HARMONIC DISTORTION TEST CIRCUIT

Analog Test Circuits (Continued)



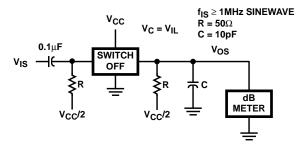
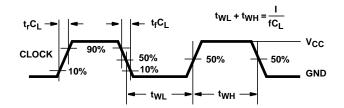


FIGURE 13. CONTROL-TO-SWITCH FEEDTHROUGH NOISE TEST CIRCUIT

FIGURE 14. SWITCH OFF SIGNAL FEEDTHROUGH

Test Circuits and Waveforms



NOTE: Outputs should be switching from 10% V $_{CC}$ to 90% V $_{CC}$ in accordance with device truth table. For f $_{MAX}$, input duty cycle = 50%.

FIGURE 15. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

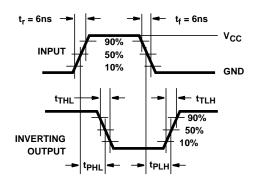


FIGURE 17. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

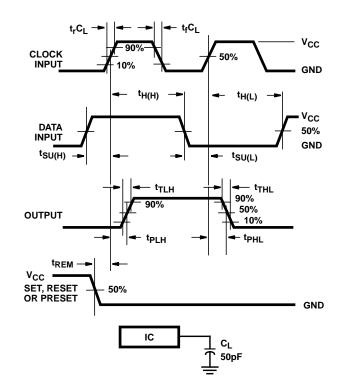
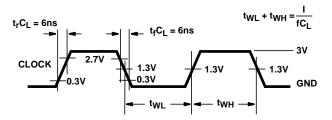


FIGURE 19. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS



NOTE: Outputs should be switching from 10% V $_{CC}$ to 90% V $_{CC}$ in accordance with device truth table. For f $_{MAX}$, input duty cycle = 50%.

FIGURE 16. HCT CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

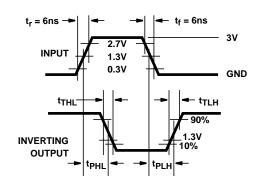


FIGURE 18. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

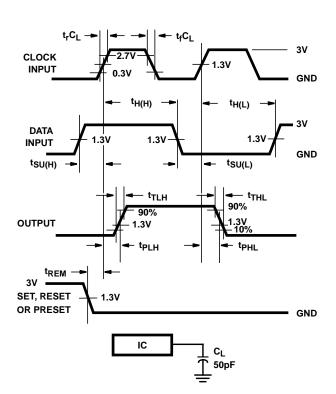
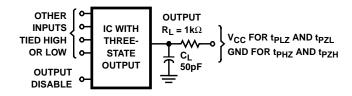


FIGURE 20. HCT SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

Test Circuits and Waveforms (Continued) 6ns 3V V_{CC} OUTPUT OUTPUT 90% **DISABLE** 50% DISABLE 10% 0.3 GND GND t_{PZL} → - t_{PLZ} → t_{PZL} ► t_{PLZ} → **OUTPUT LOW** OUTPUT LOW 50% TO OFF TO OFF 1.3V 10% 10% ◆ t_{PHZ} ◆ - t_{PZH} · t_{PHZ} → tpzh -90% 90% **OUTPUT HIGH OUTPUT HIGH** 50% TO OFF TO OFF 1.3V **OUTPUTS OUTPUTS OUTPUTS OUTPUTS OUTPUTS OUTPUTS ENABLED** ENABLED **DISABLED ENABLED** DISABLED **ENABLED**

FIGURE 21. HC THREE-STATE PROPAGATION DELAY WAVEFORM

FIGURE 22. HCT THREE-STATE PROPAGATION DELAY WAVEFORM



NOTE: Open drain waveforms t_{PLZ} and t_{PZL} are the same as those for three-state shown on the left. The test circuit is Output $R_L = 1k\Omega$ to V_{CC} , $C_L = 50pF$.

FIGURE 23. HC AND HCT THREE-STATE PROPAGATION DELAY TEST CIRCUIT

PACKAGE OPTION ADDENDUM



com 24-Sep-2007

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD54HC4351F3A	ACTIVE	CDIP	J	20	1	TBD	A42 SNPB	N / A for Pkg Type
CD74HC4351E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC4351EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC4351M	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4351M96	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4351M96E4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4351M96G4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4351ME4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4351MG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC4352E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC4352EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT4351E	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT4351EE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE OPTION ADDENDUM

24-Sep-2007

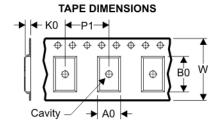
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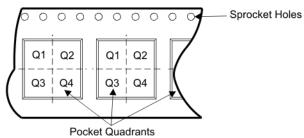
TAPE AND REEL BOX INFORMATION

REEL DIMENSIONS Reel Diameter Reel Widtle



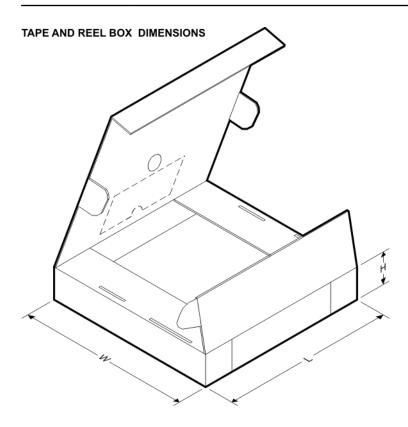
	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



Device	Package	Pins	Site	Reel Diameter (mm)	Reel Width (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC4351M96	DW	20	SITE 41	330	24	10.8	13.0	2.7	12	24	Q1





Device	Package	Pins	Site	Length (mm)	Width (mm)	Height (mm)
CD74HC4351M96	DW	20	SITE 41	346.0	346.0	0.0

14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN

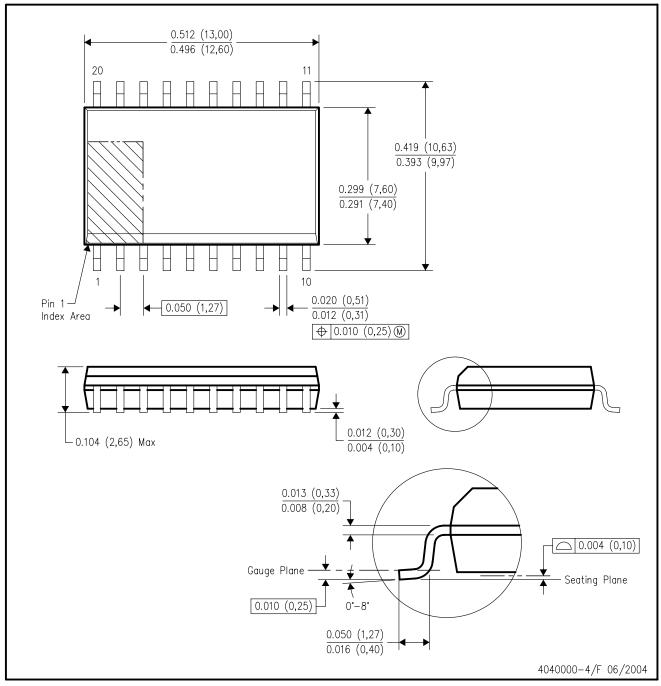


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW (R-PDSO-G20)

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



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